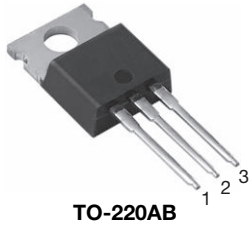
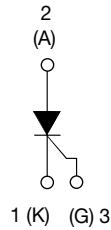




## Thyristor High Voltage, Phase Control SCR, 40 A



TO-220AB



### FEATURES

- Designed and qualified according to JEDEC-JESD47
- 140 °C max. operating junction temperature
- Material categorization:  
For definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)



**RoHS**  
COMPLIANT  
HALOGEN  
**FREE**  
Available

### APPLICATIONS

- Typical usage is in input rectification crowbar (soft start) and AC switch in motor control, UPS, welding, and battery charge

### DESCRIPTION

The VS-40TTS12... high voltage series of silicon controlled rectifiers are specifically designed for medium power switching and phase control applications. The glass passivation technology used has reliable operation up to 140 °C junction temperature.

| PRODUCT SUMMARY   |                   |
|-------------------|-------------------|
| Package           | TO-220AB          |
| Diode variation   | Single SCR        |
| $I_{T(AV)}$       | 25 A              |
| $V_{DRM}/V_{RRM}$ | 1200 V            |
| $V_{TM}$          | 1.6 V             |
| $I_{GT}$          | 35 mA             |
| $T_J$             | - 40 °C to 140 °C |

| MAJOR RATINGS AND CHARACTERISTICS |                      |             |            |
|-----------------------------------|----------------------|-------------|------------|
| PARAMETER                         | TEST CONDITIONS      | VALUES      | UNITS      |
| $I_{T(AV)}$                       | Sinusoidal waveform  | 25          | A          |
| $I_{RMS}$                         |                      | 40          |            |
| $V_{RRM}/V_{DRM}$                 |                      | 1200        | V          |
| $I_{TSM}$                         |                      | 350         | A          |
| $V_T$                             | $T_J = 25\text{ °C}$ | 1.6         | V          |
| dV/dt                             |                      | 500         | V/ $\mu$ s |
| dI/dt                             |                      | 150         | A/ $\mu$ s |
| $T_J$                             |                      | - 40 to 140 | °C         |

| VOLTAGE RATINGS              |   |  |             |
|------------------------------|---|--|-------------|
| PART NUMBER                  | $V_{RRM}$ , MAXIMUM PEAK REVERSE VOLTAGE<br>V | $V_{DRM}$ , MAXIMUM PEAK DIRECT VOLTAGE<br>V | $T_J$<br>°C |
| VS-40TTS12PbF, VS-40TTS12-M3 | 1200  | 1200   | - 25 to 140 |



| ABSOLUTE MAXIMUM RATINGS                             |                   |   |                                   |                   |
|--|-------------------|---|-----------------------------------|-------------------|
| PARAMETER  | SYMBOL            | TEST CONDITIONS   | VALUES                            | UNITS             |
| Maximum average on-state current                     | $I_{T(AV)}$       | $T_C = 93\text{ }^\circ\text{C}$ , 180° conduction half sine wave                         | 25                                | A                 |
| Maximum RMS on-state current                         | $I_{RMS}$         |   | 40                                |                   |
| Maximum peak, one-cycle non-repetitive surge current | $I_{TSM}$         | 10 ms sine pulse, rated $V_{RRM}$ applied   | 300                               |                   |
|  |                   | 10 ms sine pulse, no voltage reapplied  | 350                               |                   |
| Maximum $I^2t$ for fusing                            | $I^2t$            | 10 ms sine pulse, rated $V_{RRM}$ applied   | 450                               | A <sup>2</sup> s  |
|  |                   | 10 ms sine pulse, no voltage reapplied  | 630                               |                   |
| Maximum $I^2\sqrt{t}$ for fusing                     | $I^2\sqrt{t}$     | $t = 0.1$ to 10 ms, no voltage reapplied  | 6300                              | A <sup>2</sup> √s |
| Maximum on-state voltage                             | $V_{TM}$          | 80 A, $T_J = 25\text{ }^\circ\text{C}$  | 1.6                               | V                 |
| Low level value of on-state slope resistance         | $r_t$             | $T_J = 140\text{ }^\circ\text{C}$   | 11.4                              | mΩ                |
| Low level value of threshold voltage                 | $V_{T(TO)}$       |   | 0.96                              | V                 |
| Maximum reverse and direct leakage current           | $I_{RRM}/I_{DRM}$ | $V_R = \text{Rated } V_{RRM}/V_{DRM}$   | $T_J = 25\text{ }^\circ\text{C}$  | 0.5               |
|  |                   |   | $T_J = 140\text{ }^\circ\text{C}$ | 12                |
| Holding current                                      | $I_H$             | Anode supply = 6 V, resistive load, initial $I_T = 1$ A, $T_J = 25\text{ }^\circ\text{C}$ | 100                               | mA                |
| Maximum latching current                             | $I_L$             | Anode supply = 6 V, resistive load, $T_J = 25\text{ }^\circ\text{C}$                      | 200                               |                   |
| Maximum rate of rise of off-state voltage            | $dV/dt$           | $T_J = T_J \text{ max.}$ , linear to 80 °C, $V_{DRM} = R_g - k = \text{Open}$             | 500                               | V/μs              |
| Maximum rate of rise of turned-on current            | $dI/dt$           |   | 150                               | A/μs              |

| TRIGGERING                                  |             |  |        |       |
|---|-------------|--|--------|-------|
| PARAMETER                                   | SYMBOL      | TEST CONDITIONS  | VALUES | UNITS |
| Maximum peak gate power                     | $P_{GM}$    |  | 8.0    | W     |
| Maximum average gate power                  | $P_{G(AV)}$ |  | 2.0    |       |
| Maximum peak positive gate current          | + $I_{GM}$  |  | 1.5    | A     |
| Maximum peak negative gate voltage          | - $V_{GM}$  |  | 10     | V     |
| Maximum required DC gate current to trigger | $I_{GT}$    | Anode supply = 6 V, resistive load, $T_J = 25\text{ }^\circ\text{C}$ | 35     | mA    |
| Maximum required DC gate voltage to trigger | $V_{GT}$    | Anode supply = 6 V, resistive load, $T_J = 25\text{ }^\circ\text{C}$ | 1.3    | V     |
| Maximum DC gate voltage not to trigger      | $V_{GD}$    | $T_J = 140\text{ }^\circ\text{C}$ , $V_{DRM} = \text{Rated value}$   | 0.2    |       |
| Maximum DC gate current not to trigger      | $I_{GD}$    |  | 1.5    | mA    |

| SWITCHING                     |          |                                   |        |       |
|-------------------------------|----------|-----------------------------------|--------|-------|
| PARAMETER                     | SYMBOL   | TEST CONDITIONS                   | VALUES | UNITS |
| Typical turn-on time          | $t_{gt}$ | $T_J = 25\text{ }^\circ\text{C}$  | 0.9    | μs    |
| Typical reverse recovery time | $t_{rr}$ | $T_J = 140\text{ }^\circ\text{C}$ | 4      |       |
| Typical turn-off time         | $t_q$    |                                   | 110    |       |

| THERMAL AND MECHANICAL SPECIFICATIONS           |                |                                      |             |                        |
|---|----------------|--------------------------------------|-------------|------------------------|
| PARAMETER                                       | SYMBOL         | TEST CONDITIONS                      | VALUES      | UNITS                  |
| Maximum junction and storage temperature range  | $T_J, T_{Stg}$ |                                      | - 40 to 140 | °C                     |
| Maximum thermal resistance, junction to case    | $R_{thJC}$     | DC operation                         | 0.8         | °C/W                   |
| Maximum thermal resistance, junction to ambient | $R_{thJA}$     |                                      | 60          |                        |
| Typical thermal resistance, case to heatsink    | $R_{thCS}$     | Mounting surface, smooth and greased | 0.5         |                        |
| Approximate weight                              |                |                                      | 2           | g                      |
|   |                |                                      | 0.07        | oz.                    |
| Mounting torque                                 | minimum        |                                      | 6 (5)       | kgf · cm<br>(lbf · in) |
|   | maximum        |                                      | 12 (10)     |                        |
| Marking device                                  |                | Case style TO-220AB                  | 40TTS12     |                        |

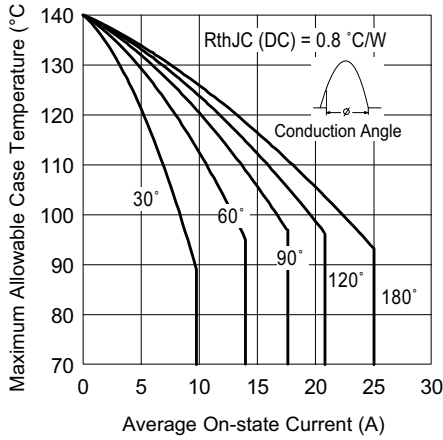


Fig. 1 - Current Rating Characteristics

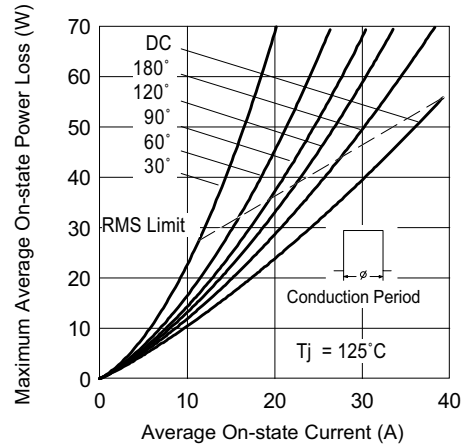


Fig. 4 - On-State Power Loss Characteristics

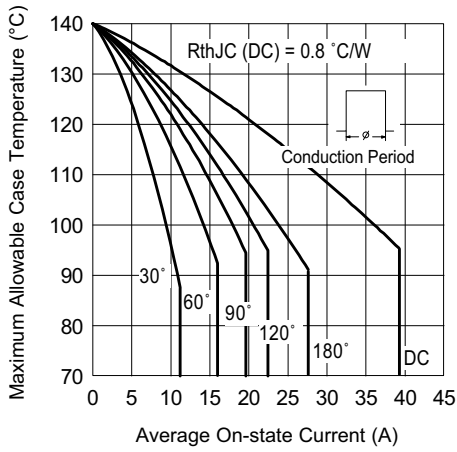


Fig. 2 - Current Rating Characteristics

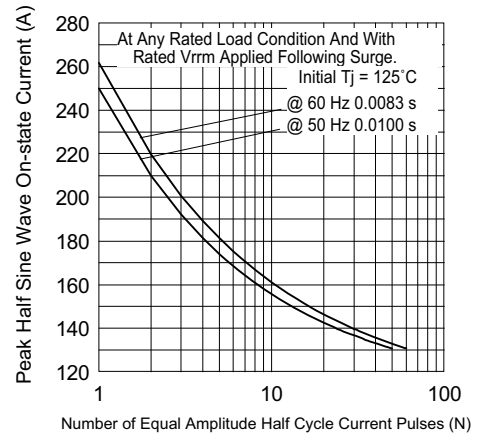


Fig. 5 - Maximum Non-Repetitive Surge Current

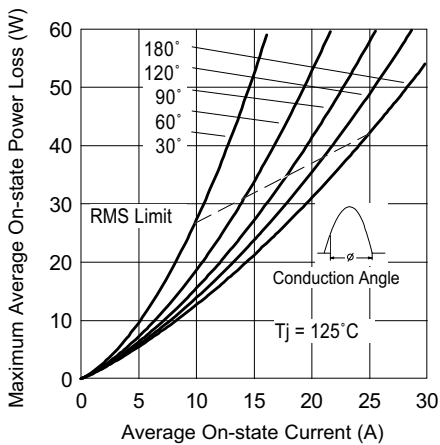


Fig. 3 - On-State Power Loss Characteristics

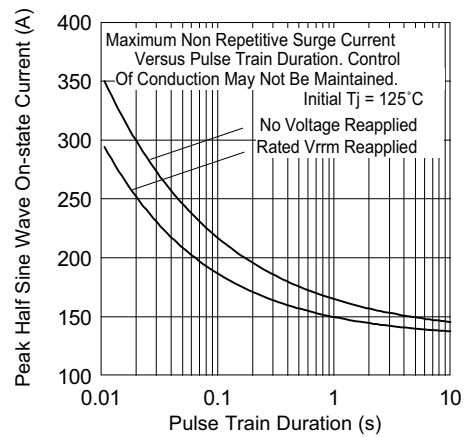


Fig. 6 - Maximum Non-Repetitive Surge Current

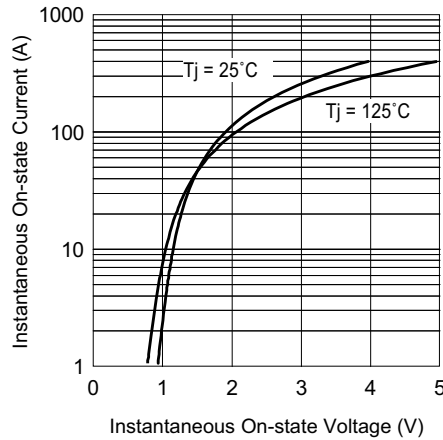


Fig. 7 - On-State Voltage Drop Characteristics

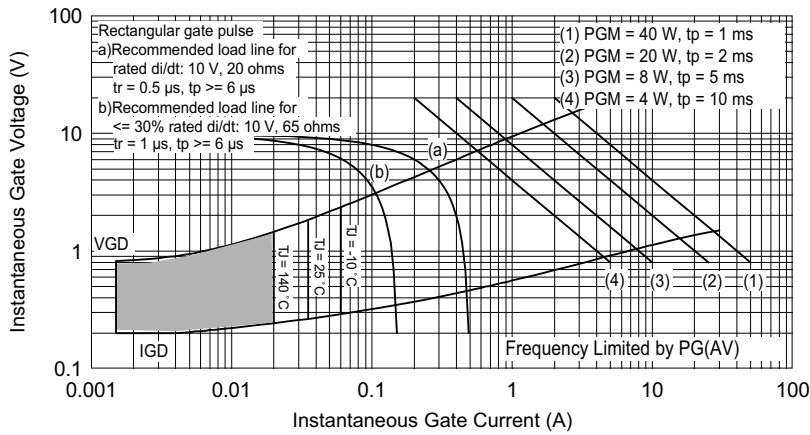


Fig. 8 - Gate Characteristics

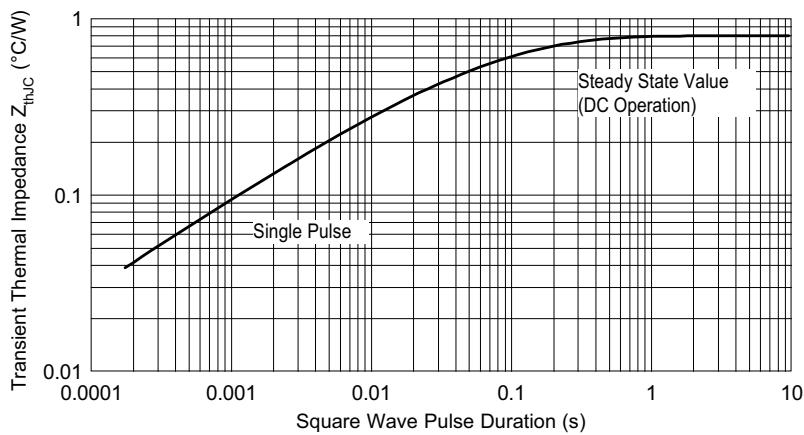
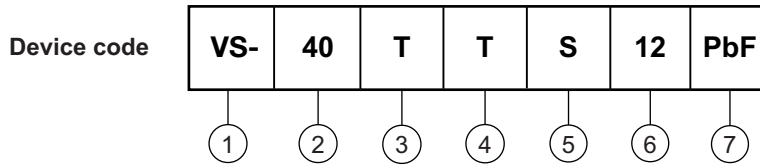


Fig. 9 - Thermal Impedance  $Z_{thJC}$  Characteristics



## ORDERING INFORMATION TABLE



- 1** - Vishay Semiconductors product
- 2** - Current rating, RMS value
- 3** - Circuit configuration:  
T = Single thyristor
- 4** - Package:  
T = TO-220
- 5** - Type of silicon:  
S = Standard recovery rectifier
- 6** - Voltage rating (12 = 1200 V)
- 7** - Environmental digit:  
PbF = Lead (Pb)-free and RoHS compliant  
-M3 = Halogen-free, RoHS compliant, and terminations lead (Pb)-free

| <b>ORDERING INFORMATION</b> (Example) |                         |                               |                              |
|---------------------------------------|-------------------------|-------------------------------|------------------------------|
| <b>PREFERRED P/N</b>                  | <b>QUANTITY PER T/R</b> | <b>MINIMUM ORDER QUANTITY</b> | <b>PACKAGING DESCRIPTION</b> |
| VS-40TTS12PbF                         | 50                      | 1000                          | Antistatic plastic tubes     |
| VS-40TTS12-M3                         | 50                      | 1000                          | Antistatic plastic tubes     |

| <b>LINKS TO RELATED DOCUMENTS</b> |              |  |
|-----------------------------------|--------------|--|
| Dimensions                        |              | <a href="http://www.vishay.com/doc?95222">www.vishay.com/doc?95222</a> |
| Part marking information          | TO-220AB PbF | <a href="http://www.vishay.com/doc?95225">www.vishay.com/doc?95225</a> |
|                                   | TO-220AB -M3 | <a href="http://www.vishay.com/doc?95028">www.vishay.com/doc?95028</a> |



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